TOSHIBA 2SD2129

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE (DARLINGTON)

2 S D 2 1 2 9

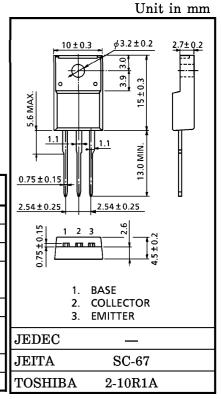
HIGH POWER SWITCHING APPLICATIONS

HAMMER DRIVE, PULSE MOTOR DRIVE APPLICATIONS

- High DC Current Gain : h_{FE} = 2000 (Min.)
- Low Saturation Voltage: V_{CE (sat)}=1.5V (Max.)

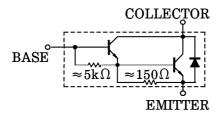
MAXIMUM RATINGS (Tc = 25°C)

CHARACTERIST	SYMBOL RATING		UNIT		
Collector-Base Voltage	v_{CBO}	100	V		
Collector-Emitter Voltage		v_{CEO}	100	V	
Emitter-Base Voltage	$V_{ m EBO}$	7	V		
Collector Current	DC	$I_{\mathbf{C}}$	3	A	
	Pulse	I_{CP}	5		
Base Current	$I_{\mathbf{B}}$	0.5	A		
Collector Power	$Ta = 25^{\circ}C$	D	2.0	W	
Dissipation	$Tc = 25^{\circ}C$	$_{ m PC}$	20		
Junction Temperature	$T_{ m j}$	150	°C		
Storage Temperature Range		$\mathrm{T_{stg}}$	T _{stg} -55~150		



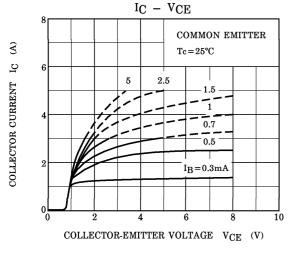
Weight: 1.7g (Typ.)

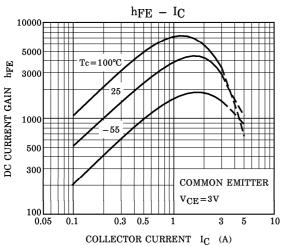
EQUIVALENT CIRCUIT

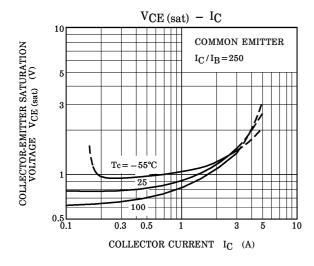


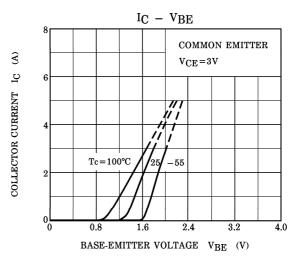
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

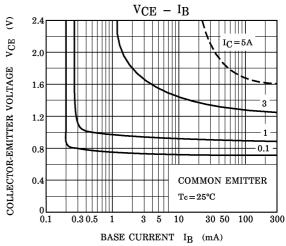
CHARAC	TERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-o	off Current	I_{CBO}	$V_{CB} = 100V, I_{E} = 0$	_	_	100	μ A
Emitter Cut-of	f Current	I_{EBO}	$V_{EB}=6V, I_{C}=0$	_	_	2.5	mA
Collector-Emit Voltage	ter Breakdown	V (BR) CEO	$I_{\rm C} = 30 {\rm mA}, \ I_{\rm B} = 0$	100	_	_	V
DC Current Gain		h _{FE (1)}	V_{CE} =3V, I_{C} =1.5A	2000	_	15000	_
		h _{FE} (2)	$V_{CE}=3V, I_{C}=3A$	1000	_	_	
Collector-Emitter Saturation		V _{CE} (sat) (1)	$I_{C} = 1.5A, I_{B} = 3mA$		_	1.5	V
Voltage		V _{CE} (sat) (2)		_	_	2.0	
Base-Emitter S Voltage	Saturation	V _{BE} (sat)	$I_{C}=1.5A, I_{B}=3mA$		_	2.0	V
Switching Time	Turn-on Time	ton	IN- OUTPUT I_{B1} I_{B2} I_{B2}		1.0	_	
	Storage Time	$t_{ ext{stg}}$		_	5.0		μ s
	Fall Time	tf	$\begin{bmatrix} I_{B1} = -I_{B2} = 3\text{mA}, & \text{W}_{CC} \\ \text{DUTY CYCLE} \leq 1\% & \vdots 30V \end{bmatrix}$	1	2.0	_	

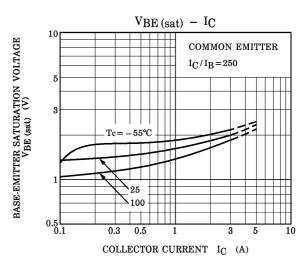


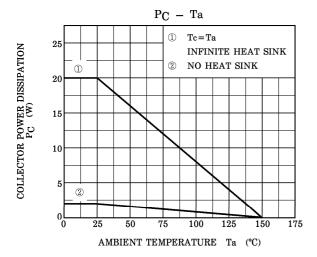


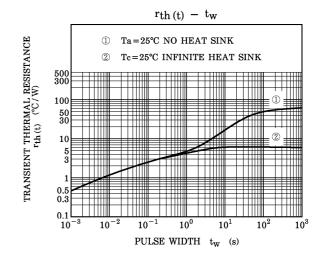


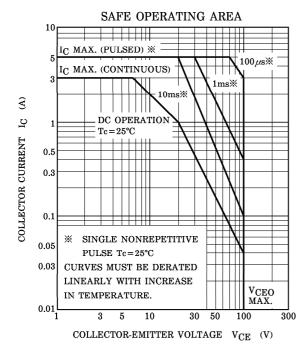












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